

60V N-Channel Enhancement Mode MOSFET

Voltage 60 V Current 6.6 A

Features

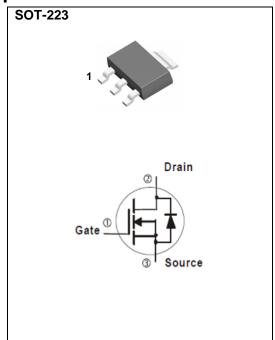
- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@6A<34m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@3A<40m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: SOT-223 Package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.043 ounces, 0.123grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	60		
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _C =25°C	l _D	6.6		
	Tc=70°C		5.3	Α	
Pulsed Drain Current (Note 1)		Ірм	26.4		
Power Dissipation	Tc=25°C	P _D	3.1	14/	
	T _C =70°C		2	W	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient (Note 3)		R _{θJA}	40.3	°C/W	

Limited only By Maximum Junction Temperature



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	60	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} ,I _D =250uA	1.0	1.83	2.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =6A	-	28	34	mΩ	
		V _{GS} =4.5V,I _D =3A		33	40		
Zero Gate Voltage Drain Current	IDSS	V _{DS} =60V,V _{GS} =0V	-	-	1.0	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 5)							
Total Gate Charge	Q_g		-	20	-	nC	
Gate-Source Charge	Qgs	V _{DS} =30V, I _D =6A, V _{GS} =10V (Note 1,2)	-	3.8	-		
Gate-Drain Charge	Q_gd	VGS=10V (1000 1,2)	-	3.9	-		
Input Capacitance	Ciss		-	1173	-	pF	
Output Capacitance	Coss	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	63	-		
Reverse Transfer Capacitance	Crss	I=I.UIVIMZ	-	44	-		
Turn-On Delay Time	td _(on)		-	7.1	-		
Turn-On Rise Time	tr	V _{DD} =15V, I _D =1A,	-	25	-	ns	
Turn-Off Delay Time	td _(off)	$V_{GS}=10V, R_{G}=6\Omega$ (Note 1,2)	-	31	-		
Turn-Off Fall Time	tf	(1000 1)2)	-	20	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	la la		-	-	6.6	А	
Diode Forward Current	ls						
Diode Forward Voltage	V _{SD}	Is=1A, V _{GS} =0V	-	0.72	1.2	V	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

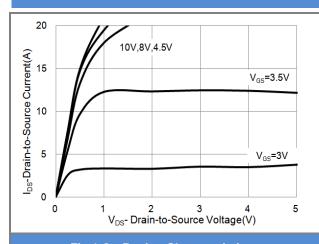


Fig.1 On-Region Characteristics

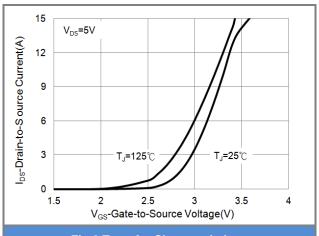


Fig.2 Transfer Characteristics

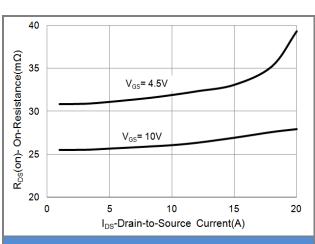


Fig.3 On-Resistance vs. Drain Current

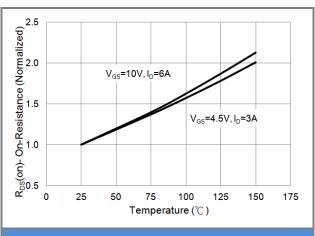


Fig.4 On-Resistance vs. Junction Temperature

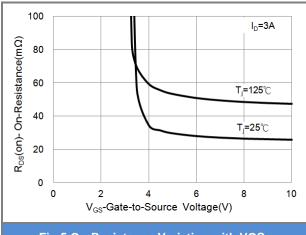


Fig.5 On-Resistance Variation with VGS.

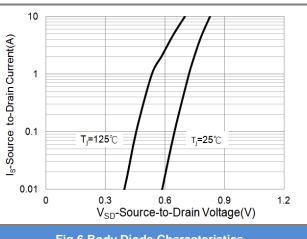


Fig.6 Body Diode Characteristics



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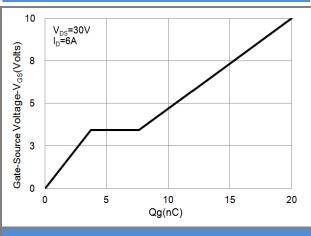


Fig.7 Gate-Charge Characteristics

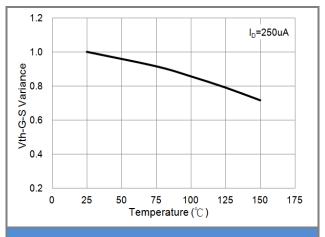


Fig.8 Threshold Voltage Variation with Temperature

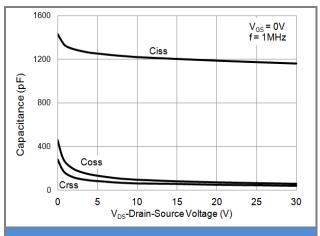
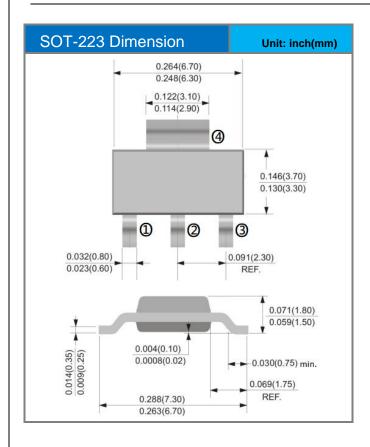
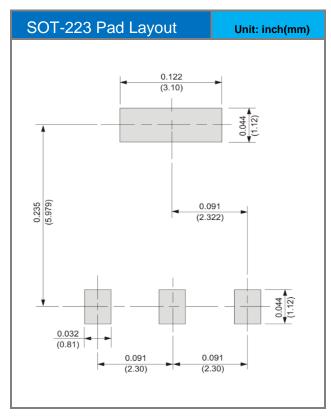


Fig.9 Capacitance vs. Drain-Source Voltage



Packaging Information & Mounting Pad Layout







Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJW7N06A	SOT-223	2,500pcs / 13" reel	W7N06A	



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